## Panasonic

# Zener Diode DE2S08200L

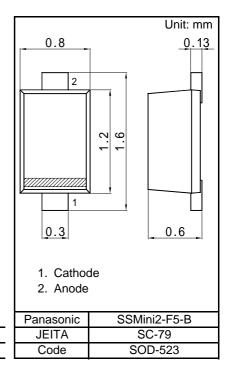
### DE2S08200L Silicon epitaxial planar type

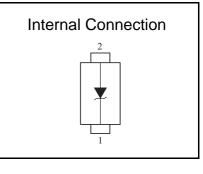
For ESD protection

- Features
- High ESD
- Halogen-free / RoHS compliant
   (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: FC

Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)





	■ Absolute Maximum Ratings Ta = 25 °C								
	Parameter	Symbol	Rating	Unit					
	Total power dissipation <sup>*1</sup>	PT	150	mW					
-	Electrostatic discharge *2	ESD	±30	kV					
	Junction temperature	Tj	150	°C					
	Operating ambient temperature	Topr	-40 to +85	°C					

 
 Storage temperature
 Tstg
 -55
 to
 +150

 Note)
 \*1: Mounted on glass epoxy print board. ( 45 mm x 45 mm x 1 mm) Solder in ( 0.8 mm x 0.6 mm)

\*2: Test method:IEC61000\_4\_2(C = 150 pF,R = 330 Ω, Contact discharge:10 times)

■ Electrical Characteristics Ta = 25 °C ± 3 °C								
	Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
	Zener voltage *1,*2	VZ	IZ = 1 mA	7.79		8.61	V	
	Reverse current	IR	VR = 5 V			0.5	μA	
	Terminal capacitance	Ct	VR = 0 V, f = 1 MHz		43		pF	
	Temperature coefficient of zener voltage *3	SZ	IZ = 1 mA		4.5		mV/°C	

°C

 Temperature coefficient of zener voltage
 SZ
 IZ = 1 mA
 4.5
 m

 Note)
 1.
 Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

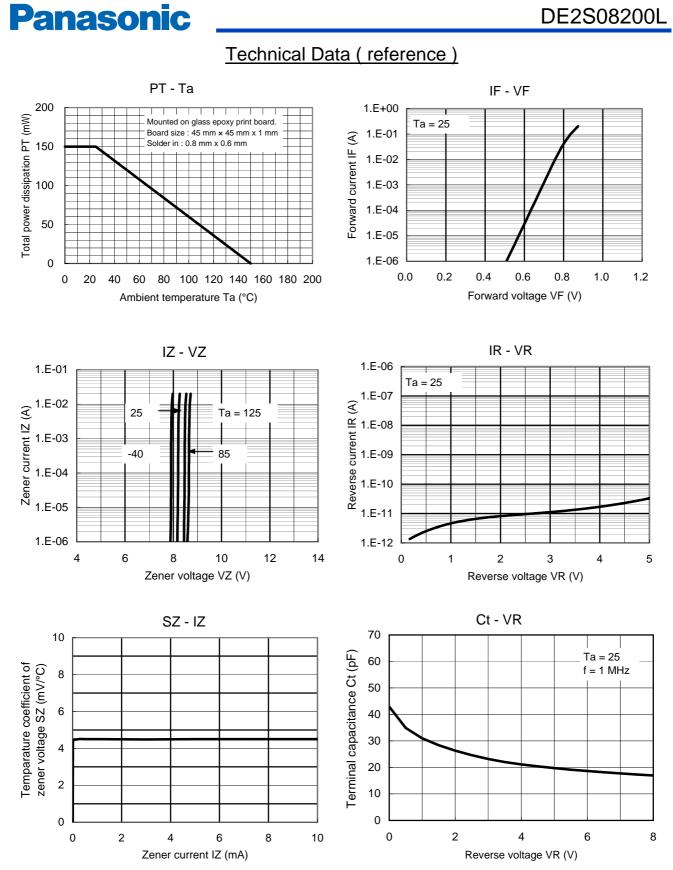
2. \*1: The temperature must be controlled 25°C for VZ mesurement.

VZ value measured at other temperature must be adjusted to VZ (25°C)

\*2: VZ guaranted 20 ms after current flow.

\*3: Tj = 25°C to 150°C

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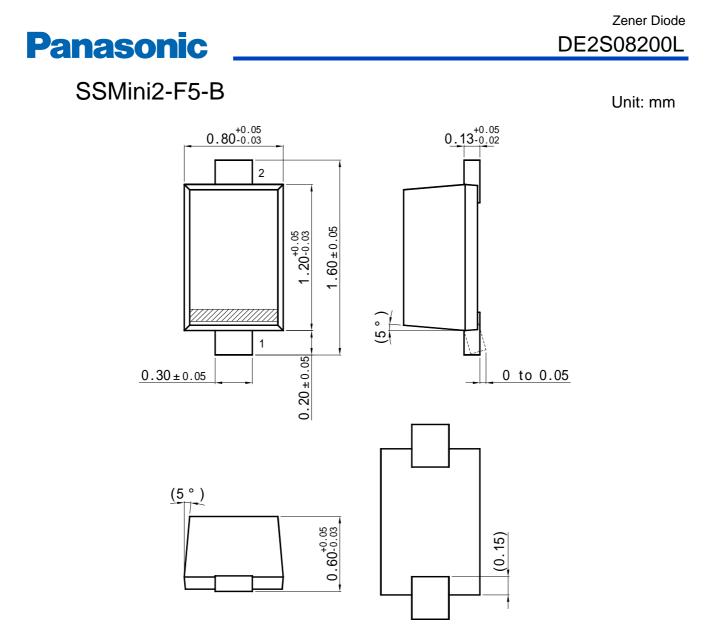


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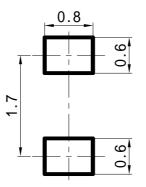
Established : 2012-10-24 Revised : 2013-11-01

#### **Panasonic** DE2S08200L Technical Data (reference) Rth - t PZSM - tw 1000 1000 (1) Ta = 25 Thermal resistance Rth (°C/W) Non-repetitive reverse surge power dissipation PZSM (W) /W Rth(j-I) = 80(2) 100 100 10 10 (1) Non-heat sink 1 (2) Mounted on glass epoxy print board. Board size : 45 mm x 45 mm x 1 mm Solder in : 0.8 mm x 0.6 mm 1 0.1 0.001 0.01 100 1000 0.1 1 10 100 1000 10000 Time t (s) Pulse width tw (µs)

Zener Diode



Land Pattern (Reference) (Unit: mm)



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